



ELECTRONICS DEVICES AND CIRCUITS

SECTION - D

SOME SPECIAL DEVICES

OBJECTIVE

DIAC

DIAC

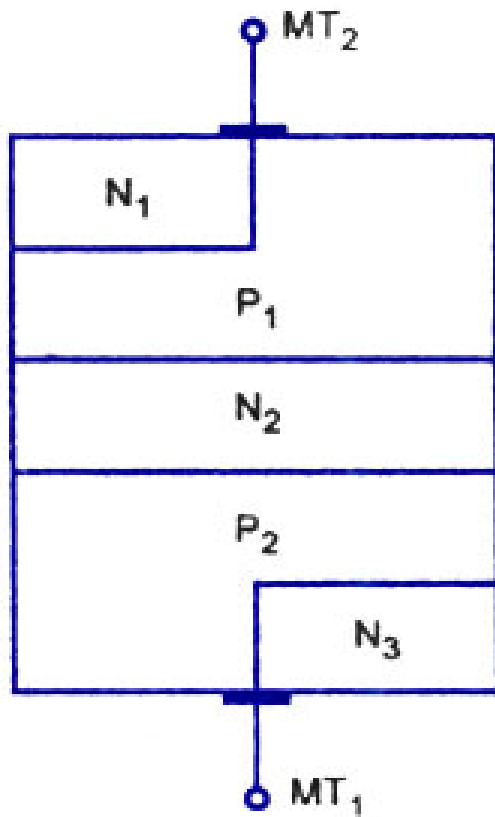
- A **DIAC** is an important member of the thyristor family and is usually employed for triggering **TRIACS**.
- A **DIAC** is a two-electrode bidirectional avalanche diode which can be switched from off-state to the on-state for either polarity of the applied voltage.
- This is just like a **TRIAC** without gate terminal.

DIAC

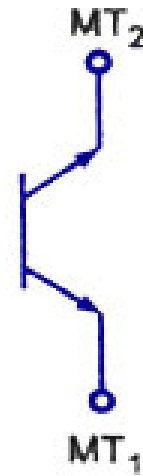
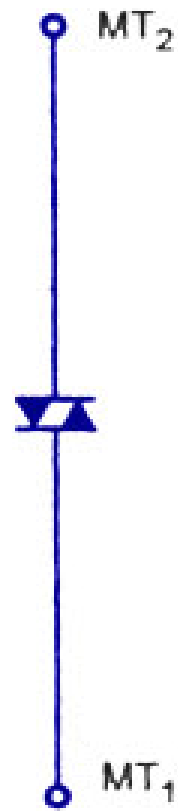
- Its equivalent circuit is a pair of inverted four layer diodes.
- Again the terminal designations are arbitrary since the **DIAC**, like **TRIAC**, is also a bilateral device.
- The switching from off-state to on-state is achieved by simply exceeding the avalanche break down voltage in either direction.

Construction of a Diac

- A **DIAC** is a P-N-P-N structured four-layer, **two-terminal** semiconductor device.
- MT2 and MT1 are the two main terminals of the device.



Basic Structure



Schematic Symbols

Diac

Construction of a Diac

- There is no control terminal in this device.
- A diac unlike a diode, resembles a bipolar junction transistor (BJT) but with the following exceptions.

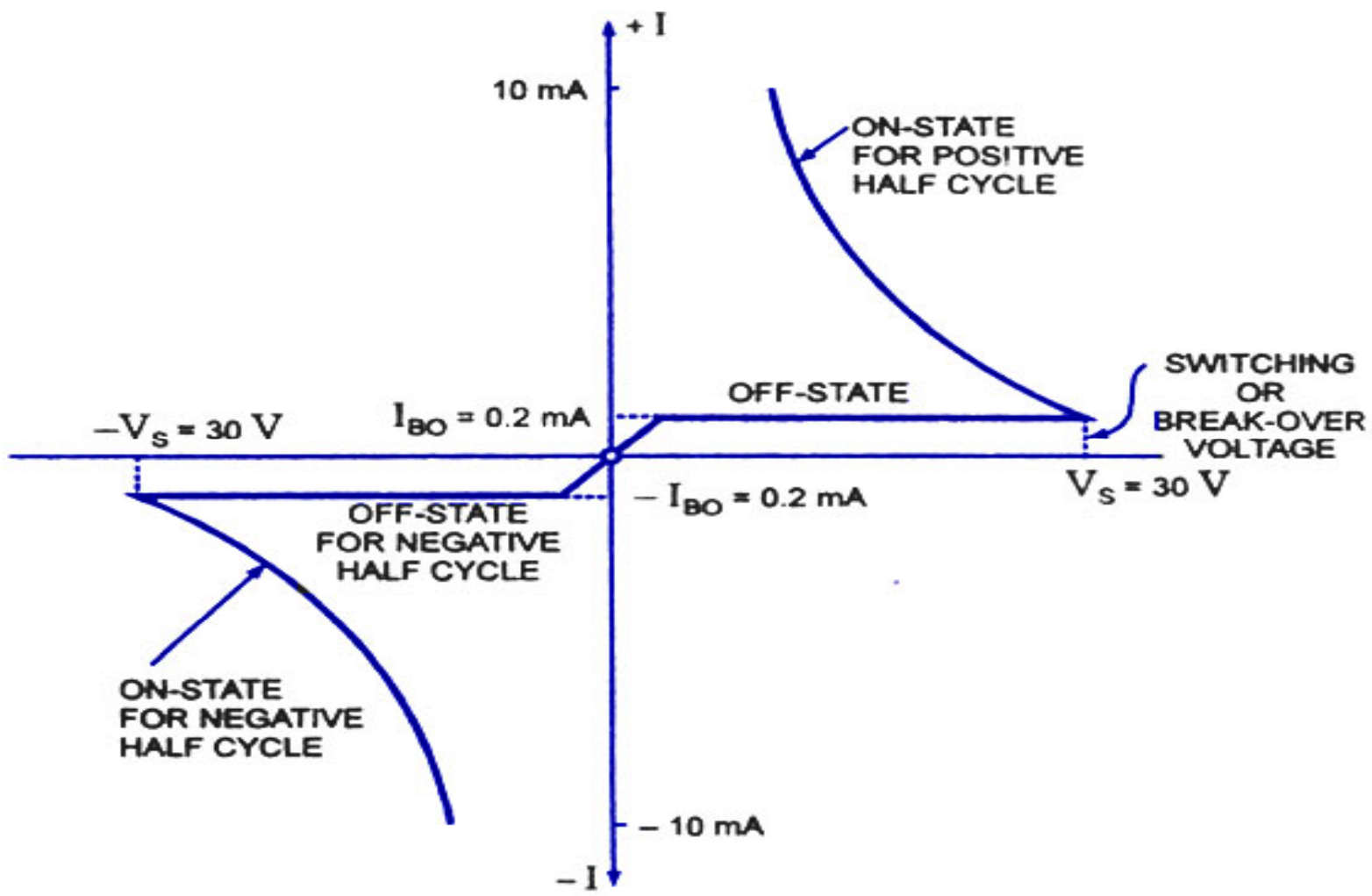
(a). There is no terminal attached to the middle layer (base),

(b). The three regions are nearly identical in size,

(c). The doping level at the two end P-layers is the same so that the device gives symmetrical switching characteristics for either polarity of the applied voltage.

Operation of a Diac

- When the terminal MT2 is positive, the current flow path is P1-N2-P2-N3 while for positive polarity of terminal MT1 the current flow path is P2-N2-P1-N1.



V-I Characteristic of a Diac

Operation of a Diac

- The operation of the **DIAC** can be explained by imagining it as two diodes connected in series.
- When applied voltage in either polarity is small (less than breakover voltage) a very small amount of current, called the ***leakage current***, flows through the device.

Conti.....

- **Leakage current** caused due to the drift of electrons and holes in the depletion region, is not sufficient to cause conduction in the device. **The device remains in non-conducting mode.**
- However, when the magnitude of the applied voltage exceeds the avalanche breakdown voltage, breakdown takes place and the **DIAC** current rises sharply.

Characteristics of a Diac

- It resembles the English letter Z because of the symmetrical switching characteristics for either polarity of the applied voltage.
- The **DIAC** acts like an open-circuit until its switching or breakover voltage is exceeded.

Characteristics of a Diac

- At that point the **DIAC** conducts until its current reduces toward zero (below the level of the holding current of the device).
- The **DIAC**, because of its peculiar construction, does not switch sharply into a low voltage condition at a low current level like the **SCR** or **TRIAC**.

Characteristics of a Diac

- Instead, once it goes into conduction, the **DIAC** maintains an almost continuous negative resistance characteristic, that is, voltage decreases with the increase in current.
- This means that, unlike the **SCR** and the **TRIAC**, the **DIAC** cannot be expected to maintain a low (on) voltage drop until its current falls below a holding current level.